TYPE 2N238/310

P-N-P ALLOY JUNCTION GERMANIUM TRANSISTOR

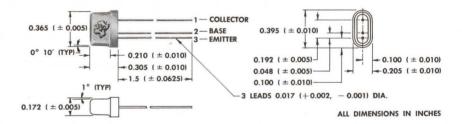


Texas Instruments Type 2N238/310 germanium P-N-P alloy junction transistor is designed for low power level Class A audio applications. Although this unit is designed for a driver application, it is also suitable as a low level Class A output device.

To guarantee maximum reliability, stability, and long life, all units are cycled from -55° C to $+75^{\circ}$ C at 95% relative humidity for four complete cycles over an eight-hour period. In addition, the hermetic seal is checked by vacuum testing.

mechanical data

Metal case with glass-to-metal hermetic seal between case and leads. Approximate weight is 1 gram.



absolute maximum ratings at 25°C ambient

Collector Voltage .											-20	V
DC Supply Voltage (For	Inc	luct	ive	Load	d)						-10	V
Device Dissipation (Free	Aiı	r)									50	mw
Operating Temperature				٠.							60	°C
Storage Temperature												$^{\circ}\mathrm{C}$

design characteristics

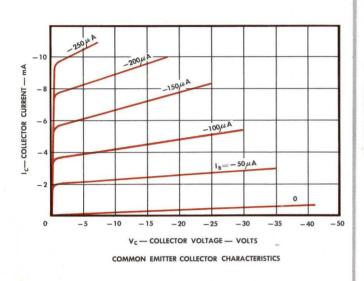
				min.	design center	max.	units
Ico	Collector Cutoff Current	$V_{CB} = -20 V$	$I_{\mathbf{F}} = 0$	_	-8	-20	μΑ
PG _e	Power Gain*	$V_{CC} = -9V$	$P_0 = 2 \text{ mW}$	37	_	42	db

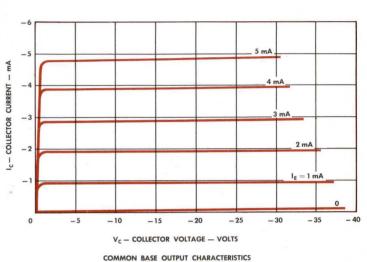
*test circuit

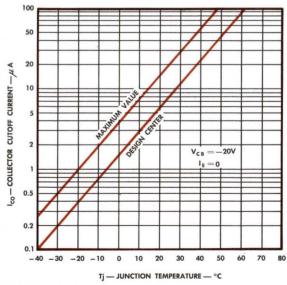
Collector Supply .		•	. –9 V	RG = 500 0 6 4fd	
Emitter Current .			. 2 mA	[M) (\$ P
Power Output .			. 2 mW		R _L = 10K
Frequency			1,000 cps	e _g (√) 15K ≥ 2.2K ≥ 476	
R _L , Collector Load			10,000 Ohms		+ 9V
Driving Impedance			. 500 Ohms	후 후	n ÷

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TYPICAL CHARACTERISTICS







COLLECTOR CUTOFF CURRENT VS. JUNCTION TEMPERATURE